Unit:mm

High Speed Switching Silicon N-channel MOSFET

DESCRIPTION

INK021ABS1 is a Silicon N-channel MOSFET.

This product is most suitable for use such as portable machinery, because voltage drive and low on resistance.

FEATURE

- •Input impedance is high, and not necessary to consider a drive electric current.
- High drain current. I_D=1.4A
- •Drive voltage 4.0V
- •Low on Resistance. RDS(on)=0.2 Ω (TYP)
- •High power Dissipation. PD=600mW

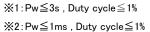
APPLICATION

Switching

TERMINAL CONNECTOR ①:SOURCE ②:DRAIN ③:GATE

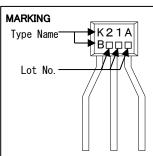
MAXIMUM RATINGS (Ta=25°C)

Parameter	Symbol	Rating	Unit	
Drain-Source Voltage	VDSS	100	V	
Gate-Source Voltage	Vgss	±20	V	
Drain Current(DC)	I D	1.4	Α	
Drain Current(Pulse)	I DP	2(※1)	Α	
		8(※2)		
Total Power Dissipation	PD	600	mW	
Channel Temperature	Tch	+150	°C	
Storage Temperature	Tstg	−55 ~ +150	°C	



EQUIVALENT CIRCUIT

OUTLINE DRAWING

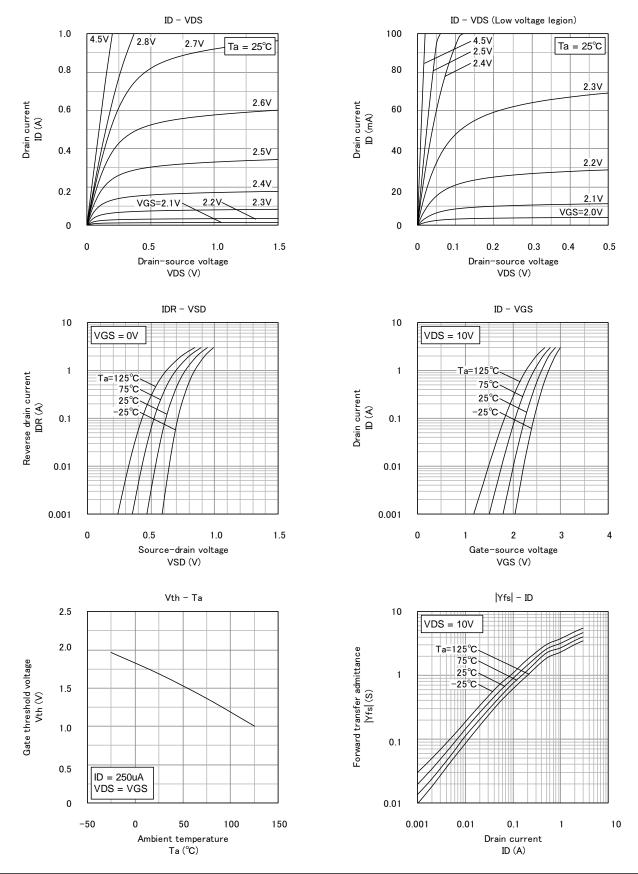


ELECTRICAL CHARACTERISTICS (Ta=25°C)

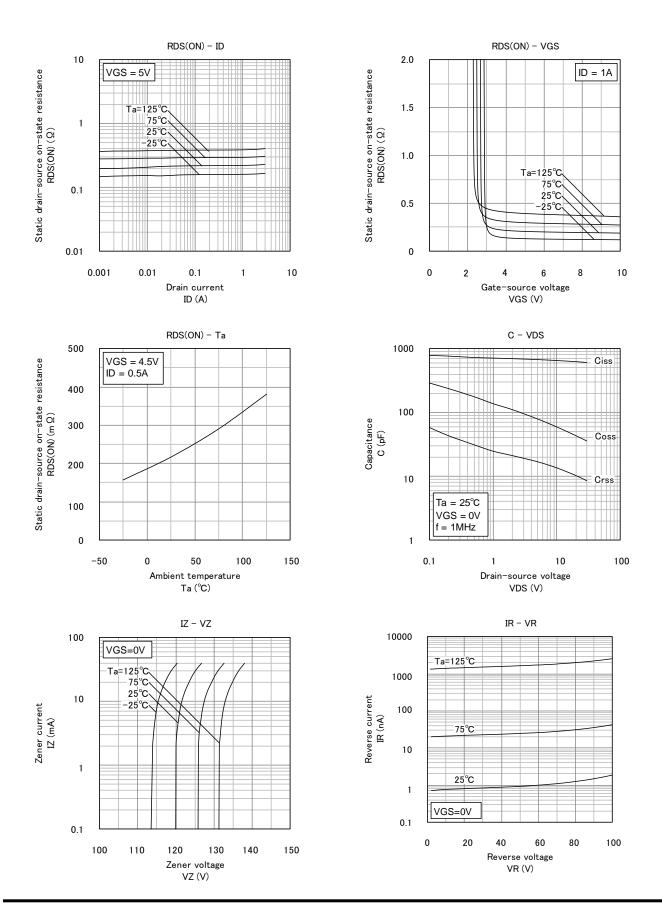
Parameter	Symbol	Test Condition		Limit		
			MIN	TYP	MAX	Unit
Drain-Source Breakdown Voltage	V(BR)DSS	I $_{D}$ =100 μ A, V $_{GS}$ =0V	100	_	_	٧
Gate-Source Leak current	Igss	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	±10	μΑ
Zero Gate Voltage Drain Current	Idss	V _{DS} =100V ,V _{GS} =0V	-	-	1.0	μΑ
Gate Threshold Voltage	Vth	I $_{D}$ =250 μ A, V $_{DS}$ = V $_{GS}$	1.0	-	2.5	٧
Forward Transfer Admittance	Yfs	V _{DS} =10V, I _D =1A	-	3.6	-	S
Static Drain-Source On-State Resistance	RDS(ON)	I _D =1A, V _{GS} =4.5V	_	0.2	0.35	Ω
Input Capacitance	Ciss	\\ -10\\\\\ -0\\\\$-1MII	_	660	_	pF
Output Capacitance	Coss	V _{DS} =10V, V _{GS} =0V,f=1MHz	-	80	-	
Switching Time	ton	V _{DD} =30V , I _D =1A	-	580	-	
	toff	V _{GS} =0∼5V	- 910	_	ns	

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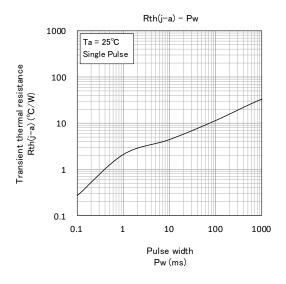
TYPICAL CHARACTERISTICS

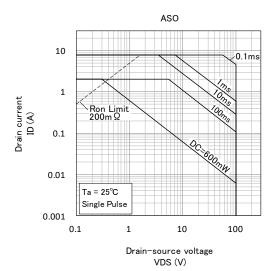


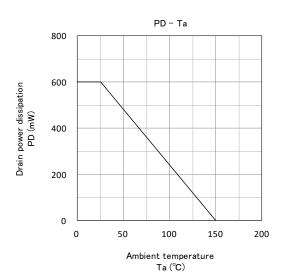
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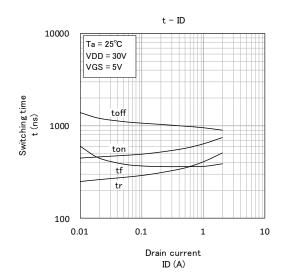


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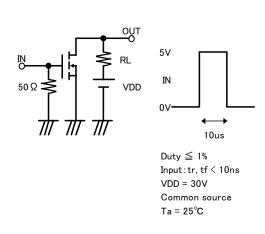


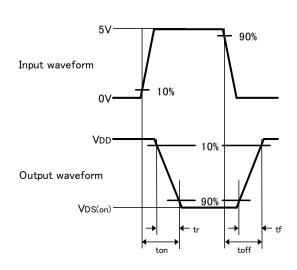






Switching time test condition





Keep safety first in your circuit designs!

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